

Very Low Dropout Bias Rail CMOS Voltage Regulator

350 mA

NCP720

The NCP720 is a 350 mA VLDO equipped with NMOS pass transistor and a separate bias supply voltage (V_{BIAS}). The device provides very stable, accurate output voltage with low noise suitable for space constrained, noise sensitive applications. In order to optimize performance for battery operated portable applications, the NCP720 features low I_Q consumption. The WDFN6 2 mm x 2 mm package is optimized for use in space constrained applications.

Features

- Input Voltage Range: 0.8 V to 5.5 V
- Bias Voltage Range: 2.4 V to 5.5 V
- Fixed Output Voltage Device
- Output Voltage Range: 0.8 V to 2.1 V
- $\pm 2\%$ Accuracy over Temperature
- Ultra-Low Dropout: 110 mV typically at 350 mA
- Very Low Bias Input Current of Typ. 80 μ A
- Very Low Bias Input Current in Disable Mode: Typ. 0.5 μ A
- Low Noise, High PSRR
- Built-In Soft-Start with Monotonic V_{OUT} Rise
- Stable with a 2.2 μ F Ceramic Capacitor
- Available in WDFN6 – 2 mm x 2 mm Package
- These are Pb-Free Devices

Typical Applications

- Battery-powered Equipment
- Smartphones, Tablets
- Cameras, DVRs, STB and Camcorders

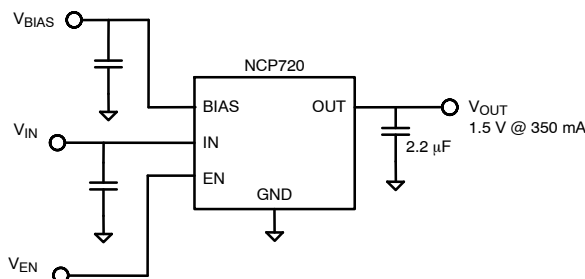
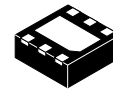
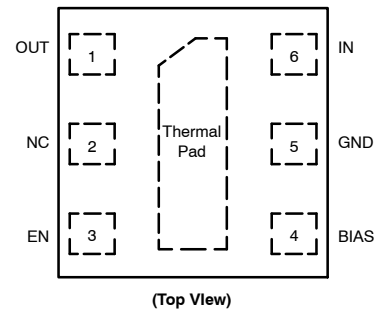


Figure 1. Typical Application Schematics

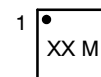


WDFN6
CASE 511BR

PIN CONNECTIONS



MARKING DIAGRAM



XX = Specific Device Code
M = Date Code

ORDERING INFORMATION

See detailed ordering, marking and shipping information on page 8 of this data sheet.

NOTE: Some of the devices on this data sheet have been **DISCONTINUED**. Please refer to the table on page 8.

NCP720

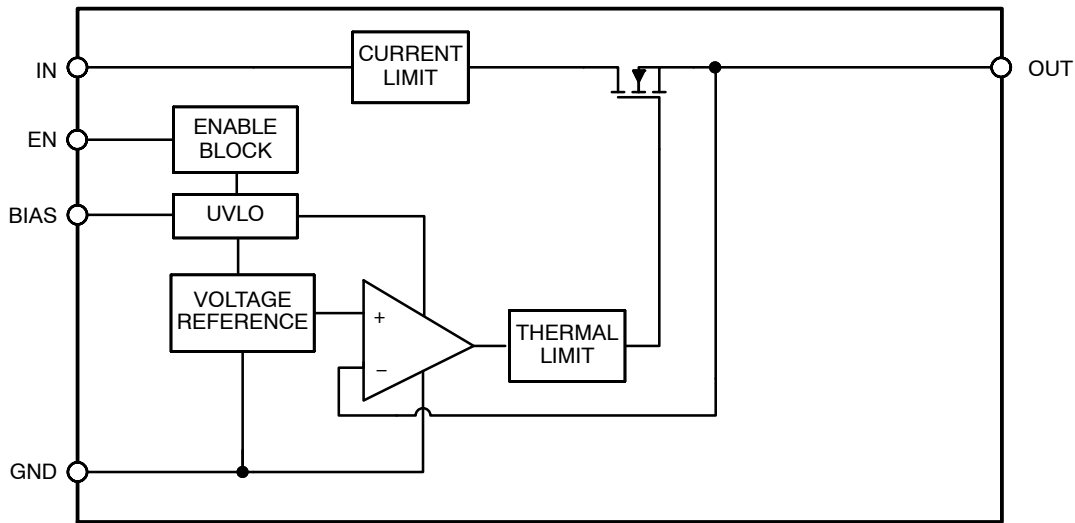


Figure 2. Simplified Schematic Block Diagram

PIN FUNCTION DESCRIPTION

Pin No.	Pin Name	Description
1	OUT	Regulated Output Voltage pin
2	N/C	Not internally connected
3	EN	Enable pin. Driving this pin high enables the regulator. Driving this pin low puts the regulator into shutdown mode.
4	BIAS	Bias voltage supply for internal control circuits. This pin is monitored by internal Under-Voltage Lockout Circuit.
5	GND	Ground pin
6	IN	Input Voltage Supply pin
Pad		Should be soldered to the ground plane for increased thermal performance.

ABSOLUTE MAXIMUM RATINGS

Symbol	Rating	Value	Unit
V_{IN}	Input Voltage (Note 1)	-0.3 to 6	V
V_{OUT}	Output Voltage	-0.3 to $(V_{IN}+0.3) \leq 6$	V
V_{EN}, V_{BIAS}	Chip Enable and Bias Input	-0.3 to 6	V
t_{SC}	Output Short Circuit Duration	unlimited	s
T_J	Maximum Junction Temperature	150	°C
T_{STG}	Storage Temperature	-55 to 150	°C
ESD_{HBM}	ESD Capability, Human Body Model (Note 2)	2000	V
ESD_{MM}	ESD Capability, Machine Model (Note 2)	200	V

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. Refer to ELECTRICAL CHARACTERISTICS and APPLICATION INFORMATION for Safe Operating Area.
2. This device series incorporates ESD protection (except OUT pin) and is tested by the following methods:
ESD Human Body Model tested per EIA/JESD22-A114
ESD Machine Model tested per EIA/JESD22-A115
Latchup Current Maximum Rating tested per JEDEC standard: JESD78.

THERMAL CHARACTERISTICS

Symbol	Rating	Value	Unit
$R_{\theta JA}$	Thermal Characteristics, WDFN6 2 mm x 2 mm Thermal Resistance, Junction-to-Air (Note 3)	65	°C/W

3. This data was derived by thermal simulations based on the JEDEC JESD51 series standards methodology. Only a single device mounted at the center of a high-K (2s2p) 3in x 3in multilayer board with 1-ounce internal planes and 2-ounce copper on top and bottom. Top copper layer has a dedicated 125 sqmm copper area.

NCP720

ELECTRICAL CHARACTERISTICS

Over Operating Temperature Range ($T_J = -40^{\circ}\text{C}$ to $+125^{\circ}\text{C}$), $V_{\text{BIAS}} = (V_{\text{OUT}} + 1.4 \text{ V})$ or 2.5 V , whichever is greater; $V_{\text{IN}} \geq V_{\text{OUT}} + 0.5 \text{ V}$, $I_{\text{OUT}} = 1 \text{ mA}$, $V_{\text{EN}} = 1.1 \text{ V}$, $C_{\text{OUT}} = 2.2 \mu\text{F}$, unless otherwise noted. Typical values are at $T_J = +25^{\circ}\text{C}$.

Symbol	Parameter		Test Conditions	Min	Typ	Max	Unit	
V _{IN}	Operating Input Voltage Range			V _{OUT} + V _{DO_IN}		5.5	V	
V _{BIAS}	Operating Bias Voltage Range			(V _{OUT} + 1.4) ≥ 2.4		5.5	V	
	Output Voltage Range (Note 4)			0.8		2.1	V	
V _{OUT}	Output Voltage Accuracy	Nominal	T _J = +25°C		±0.5		%	
V _{OUT}		Over V _{BIAS} , V _{IN} , I _{OUT} , T _J = −40°C to +125°C	V _{OUT} + 1.4 V ≤ V _{BIAS} ≤ 5.5 V, V _{OUT} + 0.5 V ≤ V _{IN} ≤ 4.5 V, 0mA ≤ I _{OUT} ≤ 350 mA	-2		+2	%	
ΔV _{OUT} /ΔV _{IN}	V _{IN} Line Regulation		V _{IN} = (V _{OUT} + 0.5 V) to 4.5 V, I _{OUT} = 1mA		5.0		μV/V	
ΔV _{OUT} /ΔV _{BIAS}	V _{BIAS} Line Regulation		V _{BIAS} = (V _{OUT} + 1.4 V) or 2.5 V (whichever is greater) to 5.5 V, I _{OUT} = 1 mA		16		μV/V	
ΔV _{OUT} /ΔI _{OUT}	Load Regulation		0 mA ≤ I _{OUT} ≤ 350 mA (no load to full load)		−1.0		μV/mA	
V _{DO_IN}	V _{IN} Dropout Voltage (Note 5)		V _{IN} = V _{OUT(NOM)} − 0.1 V, (V _{BIAS} − V _{OUT(NOM)}) = 1.4 V, I _{OUT} = 350 mA		110	200	mV	
V _{DO_BIAS}	V _{BIAS} Dropout Voltage (Note 6)		V _{IN} = V _{OUT(NOM)} + 0.3 V, I _{OUT} = 350 mA		1.15	1.4	V	
I _{CL}	Output Current Limit		V _{OUT} = 0.9 x V _{OUT(NOM)}	420	525	800	mA	
I _{BIAS}	Bias Pin Current		I _{OUT} = 0 mA to 350 mA		80	110	μA	
I _{SHDN}	Shutdown Current (I _{GND})		V _{EN} ≤ 0.4 V, T _J = -40°C to +85°C		0.5	2.0	μA	
PSRR (V _{IN})	V _{IN} Power-Supply Rejection Ratio	V _{IN} − V _{OUT} ≥ 0.5 V, V _{BIAS} = V _{OUT} + 1.4 V, I _{OUT} = 350 mA	f = 10 Hz		52		dB	
			f = 100 Hz		56			
			f = 1 kHz		65			
			f = 10 kHz		46			
			f = 100 kHz		37			
			f = 1 MHz		25			
PSRR (V _{BIAS})	V _{BIAS} Power-Supply Rejection Ratio	V _{IN} − V _{OUT} ≥ 0.5 V, V _{BIAS} = V _{OUT} + 1.4 V, I _{OUT} = 350 mA	f = 10 Hz		65		dB	
			f = 100 Hz		65			
			f = 1 kHz		70			
			f = 10 kHz		50			
			f = 100 kHz		35			
			f = 1 MHz		24			
V _N	Output Noise Voltage		BW = 10 Hz to 100 kHz			40		μV _{RMS}
I _{VIN_INRUSH}	Inrush Current on V _{IN}					100 + I _{LOAD}		mA
t _{STR}	Startup Time		V _{OUT} = 95% V _{OUT(NOM)} , I _{OUT} = 350 mA, C _{OUT} = 2.2 μF			140		μs
V _{EN(HI)}	Enable Pin High (enabled)				1.1			V
V _{EN(LO)}	Enable Pin Low (disabled)				0		0.4	V
I _{EN}	Enable Pin Current		V _{EN} = 5.5 V			0.3	1	μA
UVLO	Undervoltage Lock-out		V _{BIAS} rising			1.6		V
	Hysteresis		V _{BIAS} falling			0.2		V
T _{SD}	Thermal Shutdown Temperature		Shutdown, temperature increasing			+160		°C
			Reset, temperature decreasing			+140		°C
T _J	Operating Junction Temperature				−40		+125	°C

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

- V_{OUT} nominal value is factory programmable.
- Measured for devices with $V_{\text{OUT(NOM)}} \geq 1.2\text{V}$.
- $V_{\text{BIAS}} - V_{\text{OUT}}$ with $V_{\text{OUT}} = V_{\text{OUT(NOM)}} - 0.1\text{V}$.

APPLICATIONS INFORMATION



TYPICAL CHARACTERISTICS

$V_{OUT(NOMINAL)} = 1.5\text{ V}$, $V_{BIAS} = (V_{OUT} + 1.4\text{ V})$ OR 2.5 V , WHICHEVER IS GREATER, $V_{IN} = V_{OUT} + 0.5\text{ V}$, $I_{OUT} = 1\text{ mA}$, $V_{EN} = 1.1\text{ V}$, $C_{OUT} = 2.2\text{ MF}$, $T_J = 25^\circ\text{C}$ UNLESS OTHERWISE NOTED.

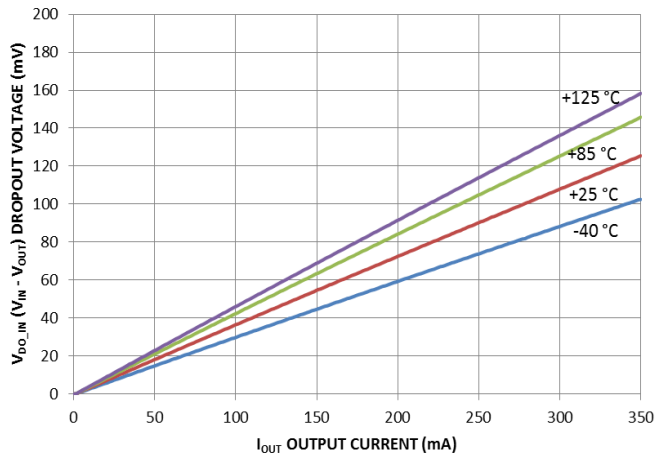


Figure 4. V_{IN} Dropout Voltage vs. Output Current

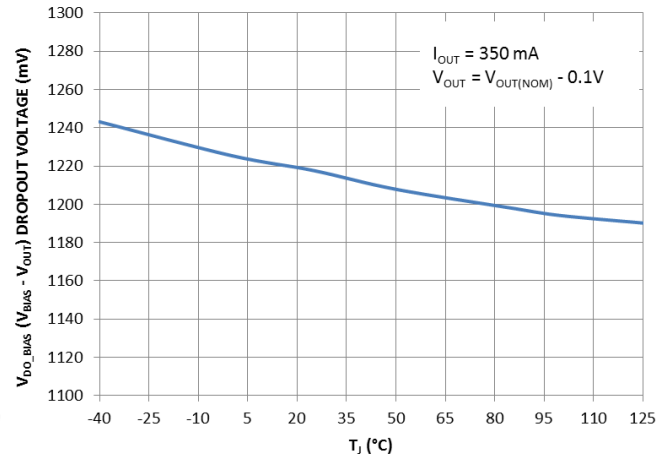


Figure 5. V_{BIAS} Dropout Voltage vs. Temperature

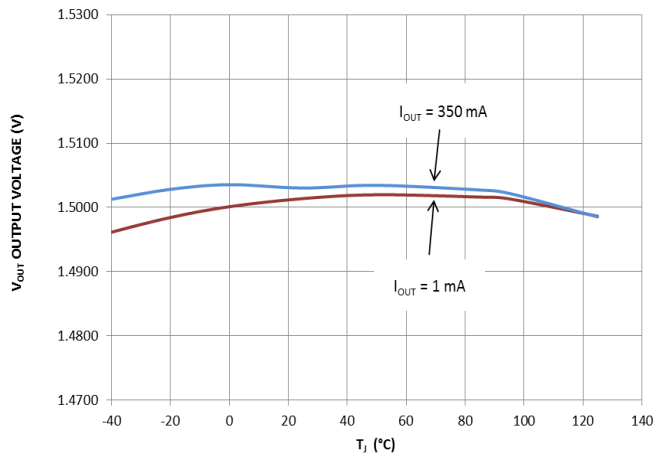


Figure 6. Output Voltage vs. Temperature

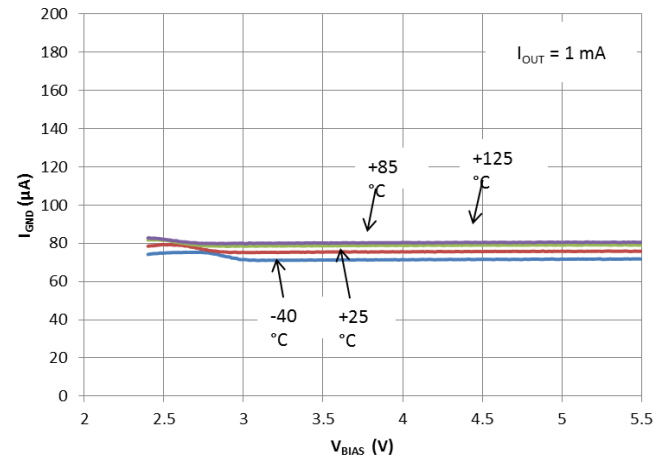


Figure 7. Bias Pin Current vs. V_{BIAS} Input Voltage

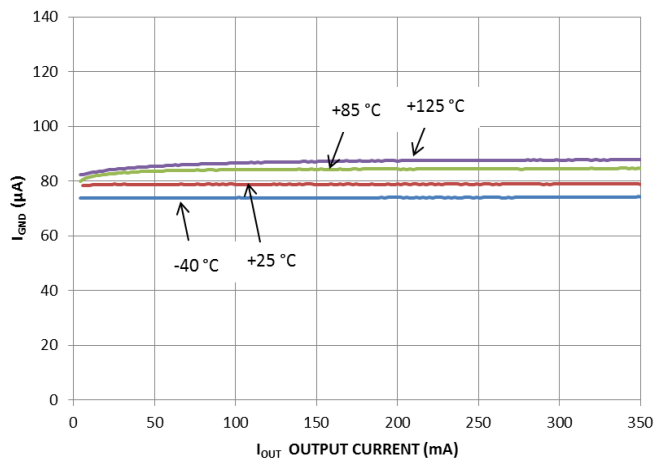


Figure 8. Bias Pin Current vs. Output Current

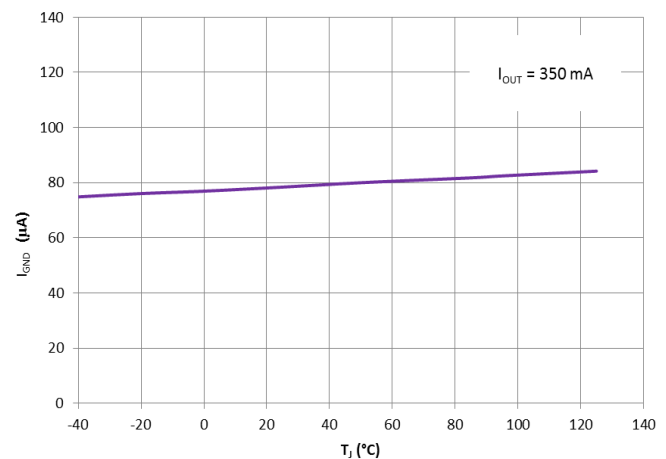


Figure 9. Bias Pin Current vs. Temperature

TYPICAL CHARACTERISTICS

$V_{OUT(NOMINAL)} = 1.5\text{ V}$, $V_{BIAS} = (V_{OUT} + 1.4\text{ V})$ OR 2.5 V , WHICHEVER IS GREATER, $V_{IN} = V_{OUT} + 0.5\text{ V}$, $I_{OUT} = 1\text{ mA}$, $V_{EN} = 1.1\text{ V}$, $C_{OUT} = 2.2\text{ MF}$, $T_J = 25^\circ\text{C}$ UNLESS OTHERWISE NOTED.

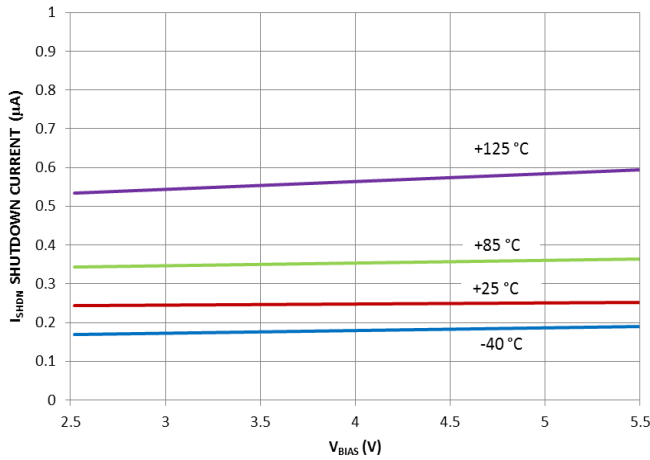


Figure 10. Shutdown Current vs. V_{BIAS} Input Voltage

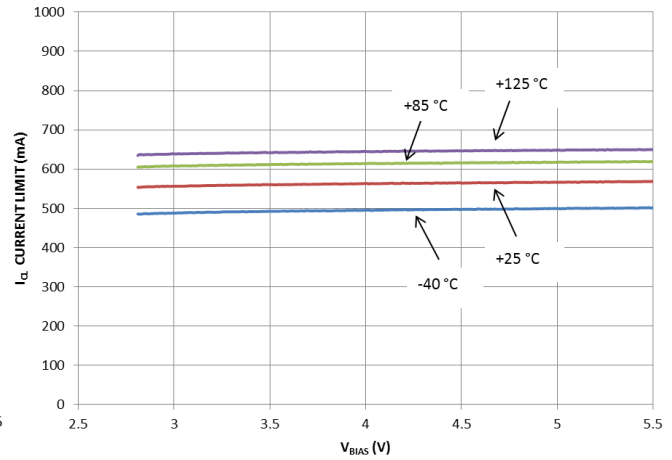


Figure 11. Current Limit vs. V_{BIAS} Input Voltage

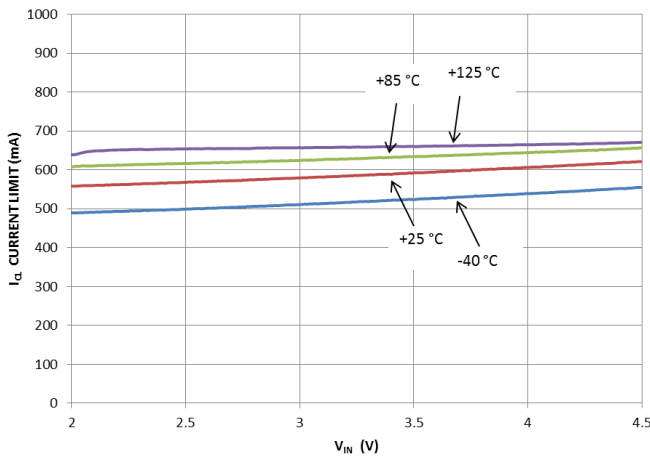


Figure 12. Current Limit vs. V_{IN} Input Voltage

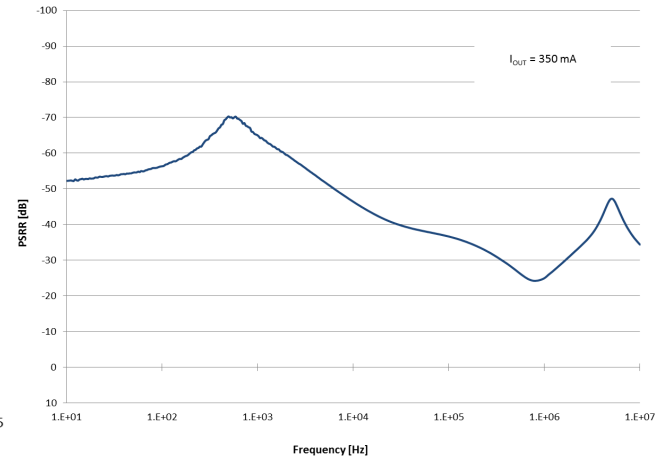


Figure 13. V_{IN} Power Supply Ripple Rejection vs. Frequency

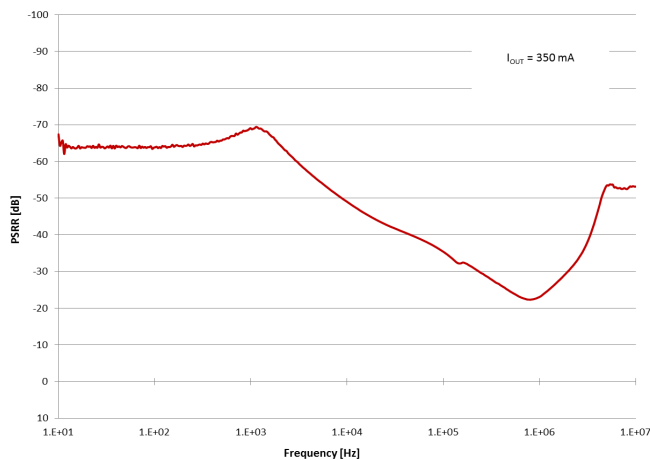


Figure 14. V_{BIAS} Power Supply Ripple Rejection vs. Frequency

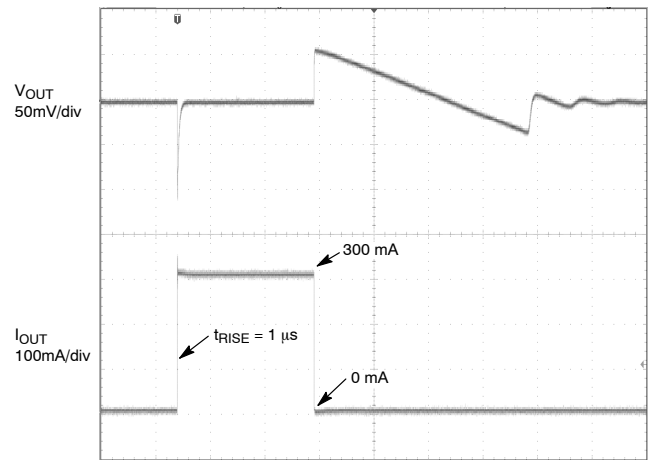


Figure 15. Load Transient Response

APPLICATIONS INFORMATION

The NCP720 dual-rail very low dropout voltage regulator is using NMOS pass transistor for output voltage regulation from V_{IN} voltage. All the low current internal control circuitry is powered from the V_{BIAS} voltage.

The use of an NMOS pass transistor offers several advantages in applications. Unlike a PMOS topology devices, the output capacitor has reduced impact on loop stability. V_{IN} to V_{OUT} operating voltage difference can be very low compared with standard PMOS regulators in very low V_{IN} applications.

The NCP720 offers built-in Soft-Start with monotonic V_{OUT} rise. The controlled voltage rising limits the inrush current.

The Enable (EN) input is equipped with internal hysteresis.

NCP720 is a Fixed Voltage linear regulator.

Dropout Voltage

Because of two power supply inputs V_{IN} and V_{BIAS} and one V_{OUT} regulator output, there are two Dropout voltages specified.

The first, the V_{IN} Dropout voltage is the voltage difference ($V_{IN} - V_{OUT}$) at which the regulator output no longer maintains regulation against further reductions in input voltage. V_{BIAS} is high enough, specific value is published in the Electrical Characteristics table.

The second, V_{BIAS} dropout voltage is the voltage difference ($V_{BIAS} - V_{OUT}$) at which the regulator output no longer maintains regulation against further reductions in V_{BIAS} voltage. V_{IN} is high enough.

Input and Output Capacitors

The device is designed to be stable for ceramic output capacitors with Effective capacitance in the range from $2.2\ \mu\text{F}$ to $10\ \mu\text{F}$. The device is also stable with multiple capacitors in parallel, having the total effective capacitance in the specified range.

In applications where no low input supplies impedance available (PCB inductance in V_{IN} and/or V_{BIAS} inputs as

example), the recommended $C_{IN} = 1\ \mu\text{F}$ and $C_{BIAS} = 0.1\ \mu\text{F}$ or greater. Ceramic capacitors are recommended. For the best performance all the capacitors should be connected to the NCP720 respective pins directly in the device PCB copper layer, not through vias having not negligible impedance.

When using small ceramic capacitor, their capacitance is not constant but varies with applied DC biasing voltage, temperature and tolerance. The effective capacitance can be much lower than their nominal capacitance value, most importantly in negative temperatures and higher LDO output voltages. That is why the recommended Output capacitor capacitance value is specified as Effective value in the specific application conditions.

Enable Operation

The enable pin will turn the regulator on or off. The threshold limits are covered in the electrical characteristics table in this data sheet. If the enable function is not to be used then the pin should be connected to V_{IN} or V_{BIAS} . When enabled, the device consumes roughly $20\ \mu\text{A}$ from V_{IN} supply per 1 V nominal output voltage. That is why using the enable / disable function in power saving applications is recommended.

Current Limitation

The internal Current Limitation circuitry allows the device to supply the full nominal current and surges but protects the device against Current Overload or Short.

Thermal Protection

Internal thermal shutdown (TSD) circuitry is provided to protect the integrated circuit in the event that the maximum junction temperature is exceeded. When TSD activated, the regulator output turns off. When cooling down under the low temperature threshold, device output is activated again. This TSD feature is provided to prevent failures from accidental overheating.

NCP720

ORDERING INFORMATION

Device	Nominal Output Voltage	Marking	Package	Shipping [†]
NCP720BMT120TBG	1.20 V	JG	WDFN6 (Pb-Free)	3,000 / Tape & Reel

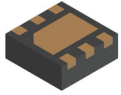
DISCONTINUED (Note 10)

NCP720BMT100TBG	1.00 V	JC	WDFN6 (Pb-Free)	3,000 / Tape & Reel
NCP720BMT105TBG	1.05 V	JD		
NCP720BMT110TBG	1.10 V	JE		
NCP720BMT115TBG	1.15 V	JF		
NCP720BMT125TBG	1.25 V	JH		
NCP720BMT130TBG	1.30 V	JJ		
NCP720BMT135TBG	1.35 V	JK		
NCP720BMT140TBG	1.40 V	JL		
NCP720BMT145TBG	1.45 V	JM		
NCP720BMT150TBG	1.50 V	JA		
NCP720BMT160TBG	1.60 V	JP		
NCP720BMT170TBG	1.70 V	JQ		
NCP720BMT180TBG	1.80 V	JR		

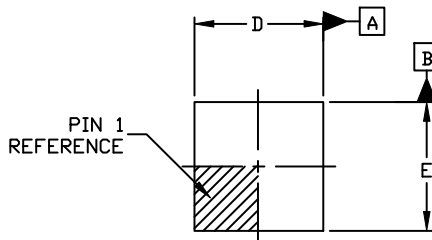
†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, [BRD8011/D](#).

7. **DISCONTINUED:** These devices are not recommended for new design. Please contact your **onsemi** representative for information. The most current information on these devices may be available on www.onsemi.com.

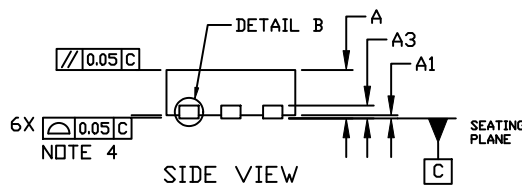
NOTE: To order other package and voltage variants, please contact your ON sales representative.


WDFN6 2x2, 0.65P
CASE 511BR
ISSUE C

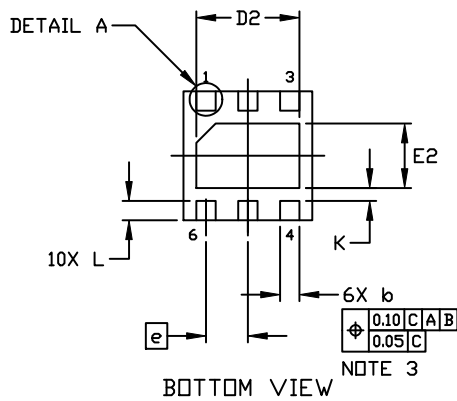
DATE 01 DEC 2021



TOP VIEW



SIDE VIEW



BOTTOM VIEW

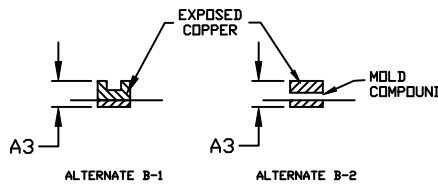
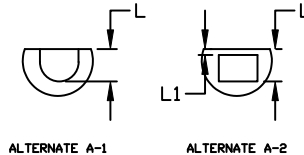
GENERIC
MARKING DIAGRAM*

XX = Specific Device Code
M = Date Code

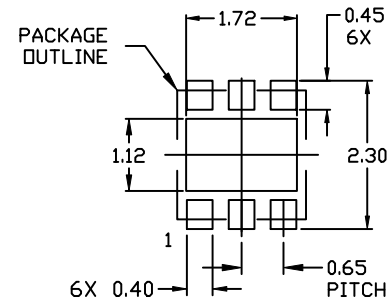
*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.

NOTES:

1. DIMENSION AND TOLERANCING PER ASME Y14.5, 2009.
2. CONTROLLING DIMENSION: MILLIMETERS
3. DIMENSION b APPLIES TO PLATED TERMINAL AND IS MEASURED BETWEEN 0.15 AND 0.30 MM FROM THE TERMINAL TIP.
4. COPLANARITY APPLIES TO THE EXPOSED PAD AS WELL AS THE TERMINALS.


DETAIL B
ALTERNATE CONSTRUCTION

DETAIL A
ALTERNATE CONSTRUCTIONS

DIM	MILLIMETERS		
	MIN.	NOM.	MAX.
A	0.70	0.75	0.80
A1	0.00	---	0.05
A3	0.20 REF		
b	0.25	0.30	0.35
D	1.90	2.00	2.10
D2	1.50	1.60	1.70
E	1.90	2.00	2.10
E2	0.90	1.00	1.10
e	0.65 BSC		
K	0.20 REF		
L	0.20	0.30	0.40
L1	---	---	0.15


RECOMMENDED
MOUNTING FOOTPRINT

For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

DOCUMENT NUMBER:	98AON55829E	Electronic versions are uncontrolled except when accessed directly from the Document Repository. Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red.
DESCRIPTION:	WDFN6 2X2, 0.65P	PAGE 1 OF 1

onsemi and onsemi are trademarks of Semiconductor Components Industries, LLC dba onsemi or its subsidiaries in the United States and/or other countries. onsemi reserves the right to make changes without further notice to any products herein. onsemi makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does onsemi assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. onsemi does not convey any license under its patent rights nor the rights of others.

onsemi, **Onsemi**, and other names, marks, and brands are registered and/or common law trademarks of Semiconductor Components Industries, LLC dba "**onsemi**" or its affiliates and/or subsidiaries in the United States and/or other countries. **onsemi** owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of **onsemi**'s product/patent coverage may be accessed at www.onsemi.com/site/pdf/Patent-Marking.pdf. **onsemi** reserves the right to make changes at any time to any products or information herein, without notice. The information herein is provided "as-is" and **onsemi** makes no warranty, representation or guarantee regarding the accuracy of the information, product features, availability, functionality, or suitability of its products for any particular purpose, nor does **onsemi** assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using **onsemi** products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by **onsemi**. "Typical" parameters which may be provided in **onsemi** data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. **onsemi** does not convey any license under any of its intellectual property rights nor the rights of others. **onsemi** products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use **onsemi** products for any such unintended or unauthorized application, Buyer shall indemnify and hold **onsemi** and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that **onsemi** was negligent regarding the design or manufacture of the part. **onsemi** is an Equal Opportunity/Affirmative Action Employer. This literature is subject to all applicable copyright laws and is not for resale in any manner.

ADDITIONAL INFORMATION

TECHNICAL PUBLICATIONS:

Technical Library: www.onsemi.com/design/resources/technical-documentation
onsemi Website: www.onsemi.com

ONLINE SUPPORT: www.onsemi.com/support

For additional information, please contact your local Sales Representative at
www.onsemi.com/support/sales

